

Data Sheet January 2000 File Number 3939.3

30A, 400V - 600V Hyperfast Dual Diodes

The RHRG3040CC and RHRG3060CC are hyperfast diodes with soft recovery characteristics (t_{rr} < 40ns). They have half the recovery time of ultrafast diodes and are silicon nitride passivated ion-implanted epitaxial planar construction.

These devices are intended for use as freewheeling/ clamping diodes and rectifiers in a variety of switching power supplies and other power switching applications. Their low stored charge and hyperfast soft recovery minimize ringing and electrical noise in many power switching circuits, thus reducing power loss in the switching transistors.

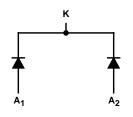
Formerly developmental type TA49063.

Ordering Information

PART NUMBER	PACKAGE	BRAND
RHRG3040CC	TO-247	RHRG3040C
RHRG3060CC	TO-247	RHRG3060C

NOTE: When ordering, use the entire part number.

Symbol



Features

•	Hyperfast with Soft Recovery
•	Operating Temperature
•	Reverse Voltage Up To
	A

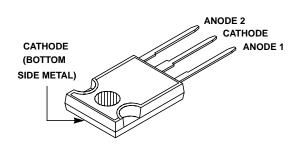
- Avalanche Energy Rated
- Planar Construction

Applications

- · Switching Power Supplies
- · Power Switching Circuits
- · General Purpose

Packaging

JEDEC STYLE TO-247



Absolute Maximum Ratings (Per Leg) $T_C = 25^{\circ}C$, Unless Otherwise Specified

	RHRG3040CC	RHRG3060CC	UNITS
Peak Repetitive Reverse VoltageV _{RRM}	400	600	V
Working Peak Reverse Voltage	400	600	V
DC Blocking Voltage	400	600	V
Average Rectified Forward Current $I_{F(AV)}$ ($T_C = 120^{\circ}C$)	30	30	Α
Repetitive Peak Surge Current	70	70	Α
Nonrepetitive Peak Surge Current	325	325	Α
Maximum Power Dissipation	125	125	W
Avalanche Energy (See Figures 10 and 11)	20	20	mJ
Operating and Storage Temperature	-65 to 175	-65 to 175	οС

RHRG3040CC, RHRG3060CC

Electrical Specifications (Per Leg) $T_C = 25^{\circ}C$, Unless Otherwise Specified

	TEST CONDITION	ı	RHRG3040CC		RHRG3060CC			
SYMBOL		MIN	TYP	MAX	MIN	TYP	MAX	UNITS
V _F	I _F = 30A	-	-	2.1	-	-	2.1	V
	I _F = 30A, T _C = 150 ^o C	-	-	1.7	-	-	1.7	V
I _R	V _R = 400V	-	-	250	-	-	-	μА
	V _R = 600V	-	-	-	-	-	250	μА
	V _R = 400V, T _C = 150°C	-	-	1.0	-	-	-	mA
	V _R = 600V, T _C = 150°C	-	-	-	-	-	1.0	mA
t _{rr}	$I_F = 1A$, $dI_F/dt = 200A/\mu s$	-	-	40	-	-	40	ns
	$I_F = 30A$, $dI_F/dt = 200A/\mu s$	-	-	45	-	-	45	ns
t _a	$I_F = 30A$, $dI_F/dt = 200A/\mu s$	-	22	-	-	22	-	ns
t _b	$I_F = 30A$, $dI_F/dt = 200A/\mu s$	-	18	-	-	18	-	ns
Q _{RR}	$I_F = 30A$, $dI_F/dt = 200A/\mu s$	-	100	-	-	100	-	nC
СЈ	V _R = 10V, I _F = 0A	-	85	-	-	85	-	pF
$R_{\theta JC}$		-	-	1.2	-	-	1.2	°C/W

DEFINITIONS

 V_F = Instantaneous forward voltage (pw = 300 μ s, D = 2%).

 I_R = Instantaneous reverse current.

t_{rr} = Reverse recovery time (See Figure 9), summation of t_a + t_b.

 t_a = Time to reach peak reverse current (See Figure 9).

 t_b = Time from peak I_{RM} to projected zero crossing of I_{RM} based on a straight line from peak I_{RM} through 25% of I_{RM} (See Figure 9).

 Q_{RR} = Reverse recovery charge.

C_J = Junction Capacitance.

 $R_{\theta JC}$ = Thermal resistance junction to case.

pw = pulse width.

D = duty cycle.

Typical Performance Curves

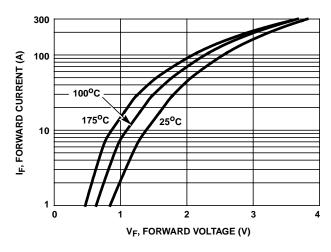


FIGURE 1. FORWARD CURRENT vs FORWARD VOLTAGE

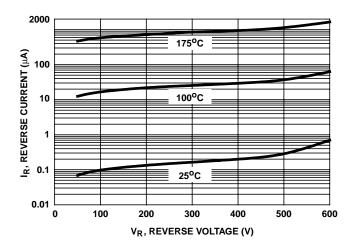


FIGURE 2. REVERSE CURRENT vs REVERSE VOLTAGE

Typical Performance Curves (Continued)

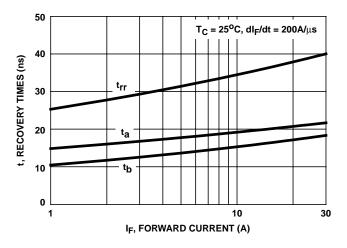


FIGURE 3. t_{rr} , t_a and t_b curves vs forward current

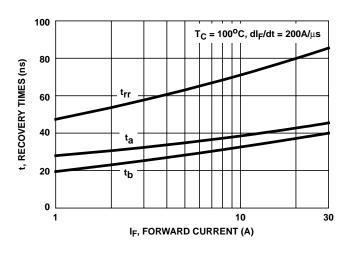


FIGURE 4. t_{rr} , t_a and t_b curves vs forward current

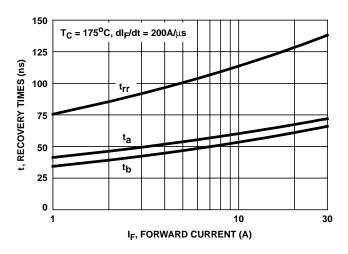


FIGURE 5. t_{rr} , t_a AND t_b CURVES vs FORWARD CURRENT

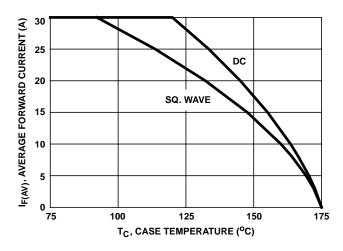


FIGURE 6. CURRENT DERATING CURVE

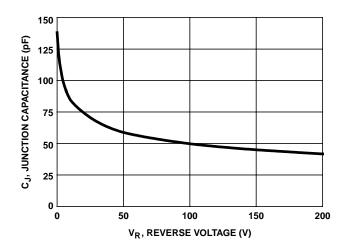


FIGURE 7. JUNCTION CAPACITANCE vs REVERSE VOLTAGE

Test Circuits and Waveforms

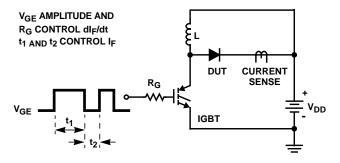


FIGURE 8. t_{rr} TEST CIRCUIT

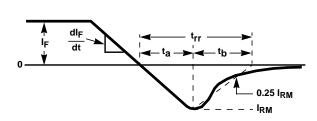


FIGURE 9. t_{rr} WAVEFORMS AND DEFINITIONS

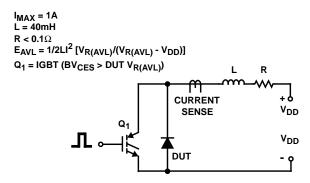


FIGURE 10. AVALANCHE ENERGY TEST CIRCUIT

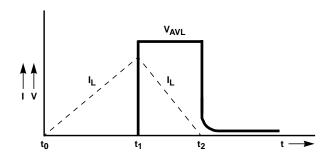


FIGURE 11. AVALANCHE CURRENT AND VOLTAGE WAVEFORMS

All Intersil semiconductor products are manufactured, assembled and tested under ISO9000 quality systems certification.

Intersil semiconductor products are sold by description only. Intersil Corporation reserves the right to make changes in circuit design and/or specifications at any time without notice. Accordingly, the reader is cautioned to verify that data sheets are current before placing orders. Information furnished by Intersil is believed to be accurate and reliable. However, no responsibility is assumed by Intersil or its subsidiaries for its use; nor for any infringements of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of Intersil or its subsidiaries.